

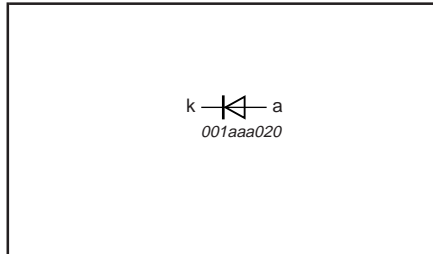
Rectifier diodes ultrafast, rugged

BYV79E series

FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

| |
|---------------------------------------|
| $V_R = 150 \text{ V} / 200 \text{ V}$ |
| $V_F \leq 0.9 \text{ V}$ |
| $I_{F(AV)} = 14 \text{ A}$ |
| $I_{RRM} \leq 0.2 \text{ A}$ |
| $t_{rr} \leq 30 \text{ ns}$ |

GENERAL DESCRIPTION

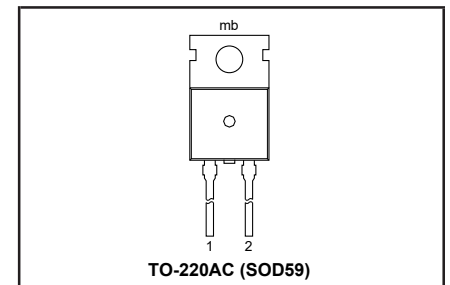
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV79E series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | cathode |
| 2 | anode |
| tab | cathode |

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | UNIT |
|-------------|--------------------------------------|--|------|-------------|-------------|------------------|
| V_{RRM} | Peak repetitive reverse voltage | BYV79E $T_{mb} \leq 145^\circ\text{C}$ | - | -150 | -200 | V |
| V_{RWM} | Crest working reverse voltage | | - | 150 | 200 | V |
| V_R | Continuous reverse voltage | | - | 150 | 200 | V |
| $I_{F(AV)}$ | Average forward current ¹ | | - | 14 | | A |
| I_{FRM} | Repetitive peak forward current | square wave $\delta = 0.5; T_{mb} \leq 120^\circ\text{C}$ $t = 25 \mu\text{s}; \delta = 0.5;$ $T_{mb} \leq 120^\circ\text{C}$ | - | 28 | | A |
| I_{FSM} | Non-repetitive peak forward current | $t = 10 \text{ ms}$ | - | 150 | | A |
| | | $t = 8.3 \text{ ms}$ sinusoidal; with reappplied $V_{RWM(max)}$ | - | 160 | | A |
| I_{RRM} | Repetitive peak reverse current | $t_p = 2 \mu\text{s}; \delta = 0.001$ | - | 0.2 | | A |
| I_{RSM} | Non-repetitive peak reverse current | $t_p = 100 \mu\text{s}$ | - | 0.2 | | A |
| T_{stg} | Storage temperature | | -40 | 150 | | $^\circ\text{C}$ |
| T_j | Operating junction temperature | | - | 150 | | $^\circ\text{C}$ |

1. Neglecting switching and reverse current losses.

ESD LIMITING VALUE

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------|---|--|------|------|------|
| V_C | Electrostatic discharge capacitor voltage | Human body model; $C = 250 \text{ pF}; R = 1.5 \text{ k}\Omega$ | - | 8 | kV |

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THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------|--|-------------|------|------|------|------|
| $R_{th\ j-mb}$ | Thermal resistance junction to mounting base | in free air | - | - | 2 | K/W |
| $R_{th\ j-a}$ | Thermal resistance junction to ambient | | - | 60 | - | K/W |

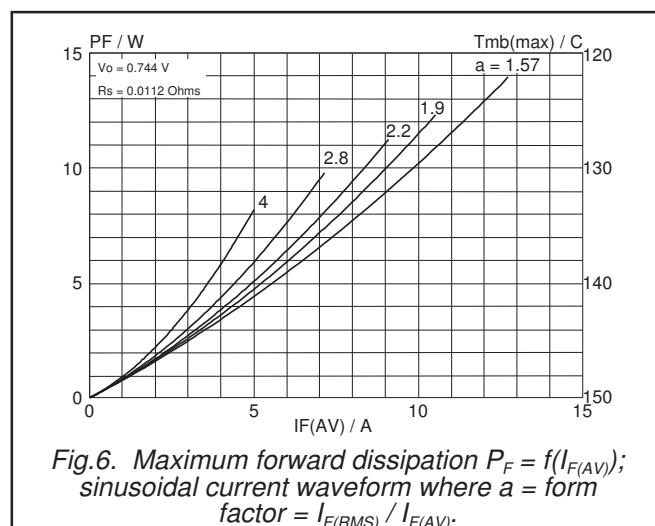
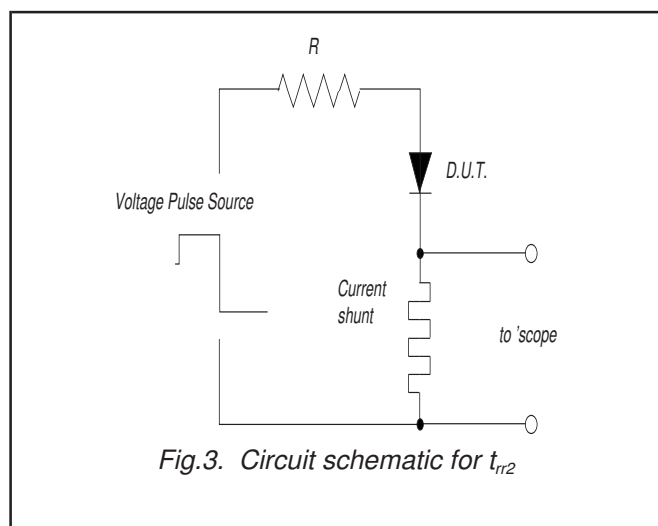
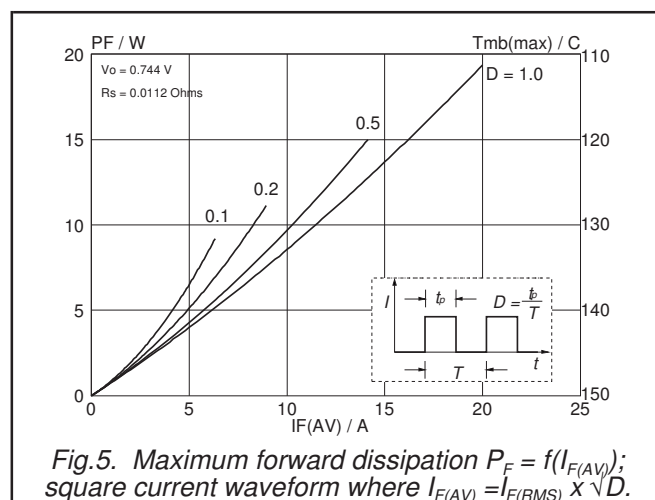
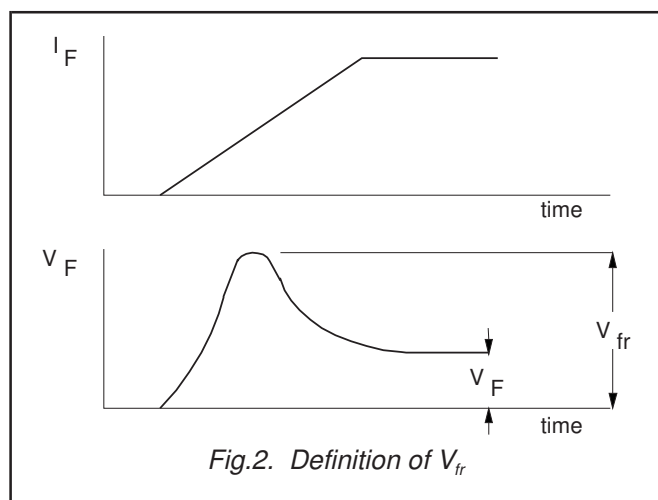
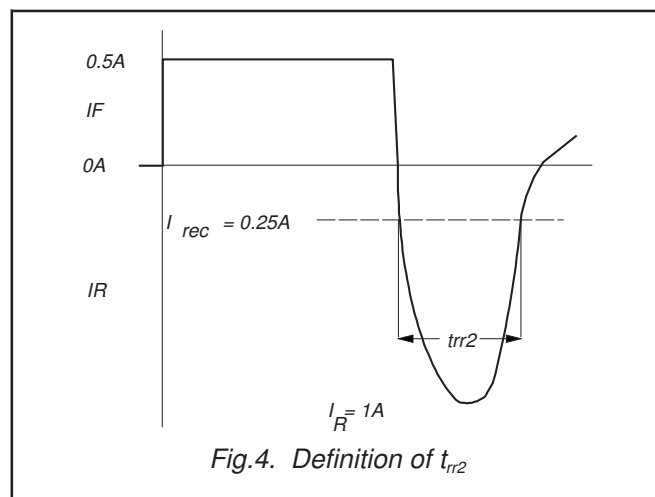
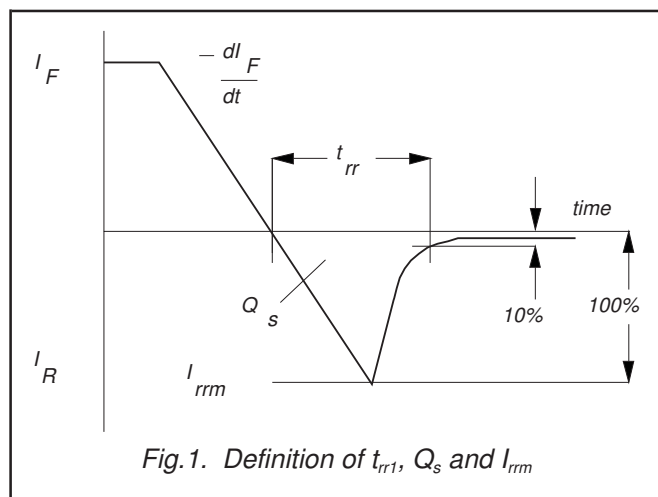
STATIC CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-----------|--------------------------|--|------|------|------|---------------|
| V_F | Forward voltage | $I_F = 14\ \text{A}; T_j = 150\ ^\circ\text{C}$ | - | 0.83 | 0.90 | V |
| | | $I_F = 14\ \text{A}$ | - | 0.95 | 1.05 | V |
| | | $I_F = 50\ \text{A}$ | - | 1.2 | 1.4 | V |
| I_R | Reverse current | $V_R = V_{RWM}; T_j = 100\ ^\circ\text{C}$ | - | 0.5 | 1.3 | mA |
| | | $V_R = V_{RWM}$ | - | 5 | 50 | μA |
| Q_s | Reverse recovery charge | $I_F = 2\ \text{A}; V_R \geq 30\ \text{V}; -dI_F/dt = 20\ \text{A}/\mu\text{s}$ | - | 6 | 15 | nC |
| t_{rr1} | Reverse recovery time | $I_F = 1\ \text{A}; V_R \geq 30\ \text{V}; -dI_F/dt = 100\ \text{A}/\mu\text{s}$ | - | 20 | 30 | ns |
| t_{rr2} | Reverse recovery time | $I_F = 0.5\ \text{A to } I_R = 1\ \text{A}; I_{rec} = 0.25\ \text{A}$ | - | 13 | 22 | ns |
| V_{fr} | Forward recovery voltage | $I_F = 1\ \text{A}; dI_F/dt = 10\ \text{A}/\mu\text{s}$ | - | 1 | - | V |

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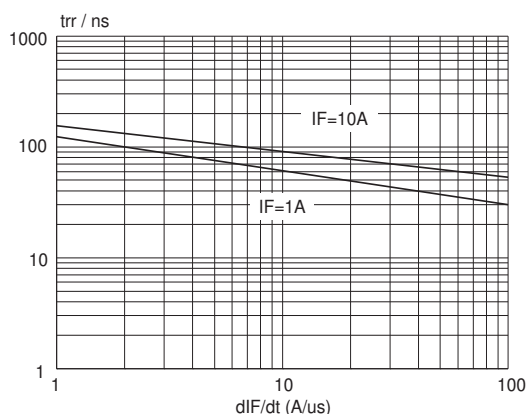


Fig.7. Maximum t_{rr} at $T_j = 25\text{ °C}$.

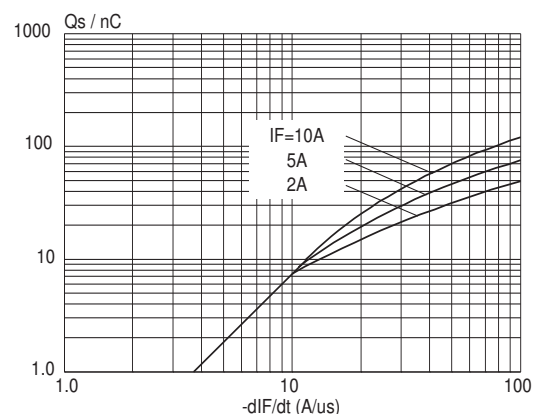


Fig.10. Maximum Q_s at $T_j = 25\text{ °C}$.

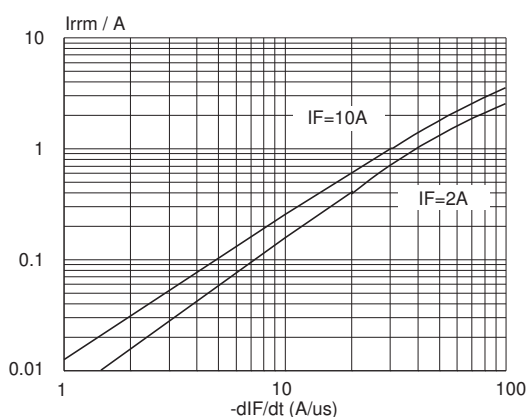


Fig.8. Maximum I_{rrm} at $T_j = 25\text{ °C}$.

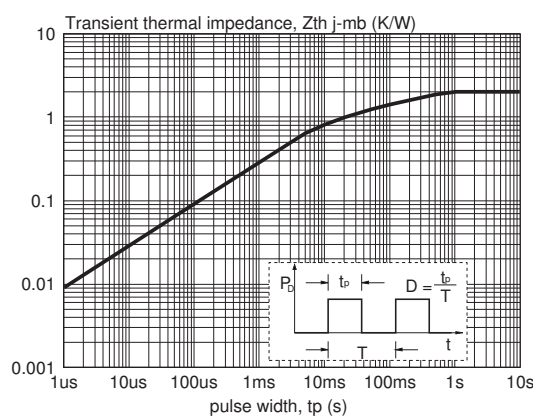


Fig.11. Transient thermal impedance; $Z_{th\ j-mb} = f(t_p)$.

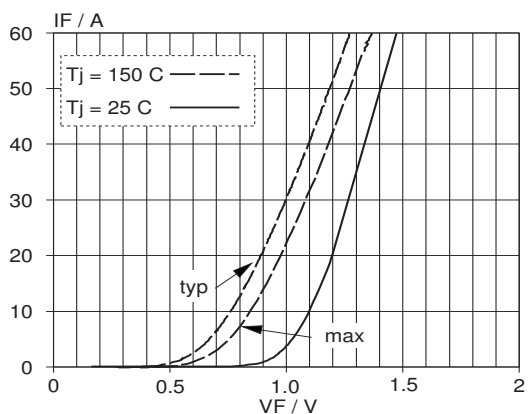


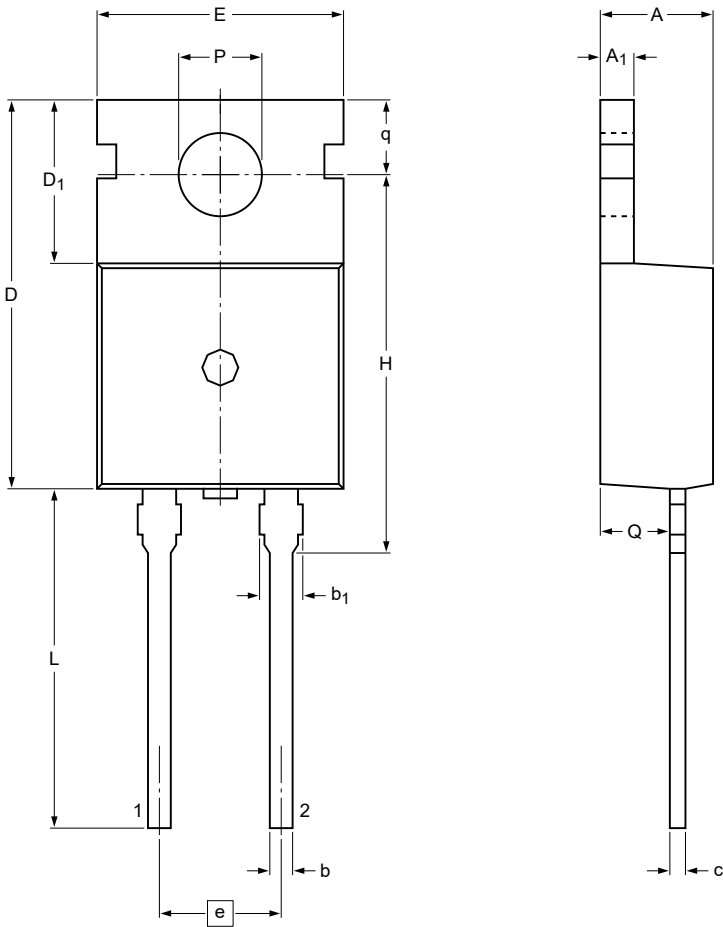
Fig.9. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

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MECHANICAL DATA

Plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC SOD59



Dimensions

| Unit | A | A ₁ | b | b ₁ (1) | c | D | D ₁ | E | e | H | L | P | Q | q |
|------|-----|----------------|------|--------------------|-----|------|----------------|-----|-------|-------|------|------|-----|-----|
| mm | max | 4.7 | 1.40 | 0.95 | 1.7 | 0.65 | 15.8 | 6.8 | 10.30 | 16.25 | 15.0 | 3.80 | 2.6 | 2.9 |
| | nom | | | | | | | | 5.08 | | | | | |
| | min | 4.3 | 1.15 | 0.70 | 1.3 | 0.45 | 15.6 | 6.4 | 9.65 | 15.70 | 12.5 | 3.65 | 2.2 | 2.7 |

Note

1. Protruded dambar are included in the dimension.

sod059_po

| Outline version | References | | | | European projection | Issue date |
|-----------------|------------|-----------------|-------|--|---------------------|----------------------|
| | IEC | JEDEC | JEITA | | | |
| SOD59 | | 2-lead TO-220AC | | | | 09-08-25 12-11-27 |

Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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